



Docket No.: M4065.0536/P536-B
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Hongmei Wang et al.

Application No.: 10/751,443

Confirmation No.: 2565

Filed: January 6, 2004

Art Unit: 2814

For: FULLY-DEPLETED (FD) (SOI) MOSFET
ACCESS TRANSISTOR (AS AMENDED)

Examiner: C. M. D. Pizarro

AMENDMENT AFTER FINAL ACTION (37 C.F.R. § 1.116)

MS AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

In response to the Office Action dated June 10, 2005 (Paper No. 0605), finally rejecting claims 27 and 32-35, please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 4 of this paper.